



3.0A SCHOTTKY BARRIER RECTIFIER

Product Summary

B350A	F/B360AF			
VF	RRM (V)	I _O (A)	V _F (MAX) (V) @ +25°C	I _{R(MAX)} (mA) @ +25°C
	50	3	0.65	0.2
	60	3	0.65	0.2

Description and Applications

The Schottky rectifier providing low V_F and excellent reverse leakage stability at high temperatures, this device is ideal for use in general rectification applications such as:

- Boost Diode
- Blocking Diode
- Recirculating Diode

Features and Benefits

- Reduced Low Forward Voltage Drop (V_F); Better Efficiency and Cooler Operation
- Reduced High-temperature Reverse Leakage; Increased Reliability against Thermal Runaway Failure in High Temperature Operation.
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

Mechanical Data

- Case: SMAF
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Polarity: Cathode Band
- Weight: 0.036 grams (Approximate)

SMAF



Top View

Ordering Information (Note 4)

Part Number	Case	Packaging
B350AF-13	SMAF	10,000/Tape & Reel
B360AF-13	SMAF	10,000/Tape & Reel

Notes:

- 1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
- 2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



B3XXAF = Product Type Marking Code (ex: B350AF)

| Sili = Manufacturers' Code Marking
| YWW = Date Code Marking
| Y = Last Digit of Year (ex: 7 for 2017)
| WW = Week Code (01 to 53)



Maximum Ratings (@ $T_A = +25^{\circ}C$, unless otherwise specified.)

Single phase, half wave, 60Hz, resistive or inductive load. For capacitive load, derate current by 20%.

Characteristic	Symbol	B350AF	B360AF	Unit
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	V _{RRM} V _{RWM} V _{RM}	50	60	>
Average Rectified Output Current	lo	3	3	Α
Non-Repetitive Peak Forward Surge Current 8.3ms Single Half Sine-Wave Superimposed on Rated Load	I _{FSM}	8	0	А

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Typical Thermal Resistance Junction to Ambient (Note 5)	$R_{\theta JA}$	90	°C/W
Typical Thermal Resistance Junction to Case (Note 5)	R _{0JC}	50	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Farward Valtage Dran		_	0.55	0.65	M	$I_F = 3A, T_J = +25^{\circ}C$
Forward Voltage Drop	VF	_	0.52	_	V	I _F = 3A, T _J = +125°C
B350AF		_	0.02	0.2		V _R = 50V, T _J = +25°C
Leakage Current (Note 6) B360AF	I _R	_	0.03	0.2	mA	$V_R = 60V, T_J = +25^{\circ}C$
		_	24	_		$V_R = 60V, T_J = +125$ °C
Typical Capacitance	C _T	_	110	_	pF	$V_R = 4.0V$, $f = 1MHz$

Notes:

- 5. Device mounted on FR-4 substrate, 0.4"*0.5", 2oz, single-sided, PC boards with 0.2"*0.25" copper pad. 6. Short duration pulse test used to minimize self-heating effect.



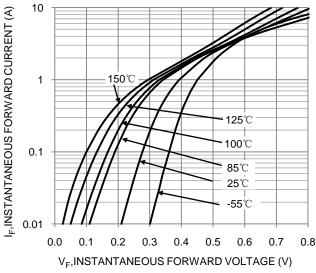
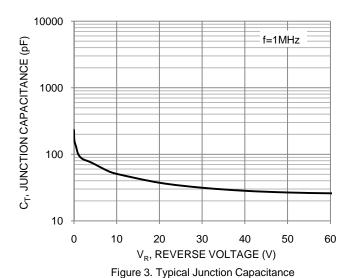


Figure 1. Typical Forward Characteristics



I_R, REVERSE LEAKAGE CURRENT (mA) 10 1 85℃ **125**℃ 100℃ 0.1 0.01 25℃ 0.001 0 10 20 30 40 50 60 V_R, REVERSE VOLTAGE (V) Figure 2. Typical Reverse Characteristics

150℃

100

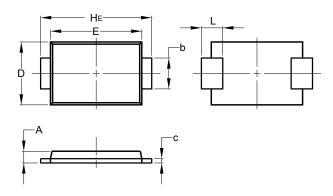
3.5 3 I_F, DC FORWARD CURRENT(A) 2.5 2 Note 5 1.5 1 0.5 0 25 150 Figure 4. DC Forward Current Derating



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SMAF

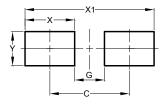


SMAF					
Dim	Min	Max			
Α	0.90	1.10			
b	1.25	1.65			
С	0.10	0.40			
D	2.25	2.95			
Е	3.95	4.60			
HE	4.80	5.60			
L	0.50	1.50			
All Dimensions in mm					

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SMAF



Dimensions	Value (in mm)
С	4.00
G	1.50
Х	2.50
X1	6.50
Υ	1 70



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